

Isc N-Channel MOSFET Transistor

IRF540ZL

D(2)

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pin 1, Oate

3

2

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2, Drain

3, Source

• FEATURES

- With To-263(D2PAK) package
- · Low input capacitance and gate charge
- Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

Switching applications

| • ABSOI | LUTE MAXIMUM RATINGS(Ta=25°C | TO-262 package | | |
|------------------|---|---|------|--|
| SYMBOL | PARAMETER | VALUE | UNIT | |
| V _{DSS} | Drain-Source Voltage | 100 | V | |
| V_{GSS} | Gate-Source Voltage | ±20 | V | |
| ID | Drain Current-ContinuousTc=25℃ Tc=100℃ | 36 25 | A | |
| I _{DM} | Drain Current-Single Pulsed | 140 | A | - mm DIM MIN MAX A 4.37 4.77 |
| PD | Total Dissipation @Tc=25°C | 92 | W | A1 1.22 1.42 A2 2.47 2.87 b 0.70 0.97 |
| T _{ch} | Max. Operating Junction Temperature | 175 | °C | b2 1.17 1.42 c 0.28 0.53 D 23.20 24.02 D1 8.38 8.90 |
| T _{stg} | Storage Temperature | -55~175 | °C | D2 6.00 - E 9.90 10.39 E4 7.30 - e 2.54BSC |
| • THERM | | $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ | | |
| SYMBOL | PARAMETER | МАХ | UNIT | L1 3.30 4.06 L3 0.95 1.15 |
| Rth(ch-c) | Channel-to-case thermal resistance | 1.64 | °C/W | - |

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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | ТҮР | МАХ | UNIT |
|----------------------|--------------------------------|--|-----|-----|-----------|------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V; I _D = 0.25mA | 100 | | | V |
| V _{GS} (th) | Gate Threshold Voltage | V _{DS} =V _{GS} ; I _D =0.25mA | 2.0 | | 4.0 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} = 10V; I _D =22A | | 21 | 26.5 | mΩ |
| I _{GSS} | Gate-Source Leakage Current | V _{GS} = ±20V;V _{DS} =0V | | | ±0.2 | μA |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} =100V; V _{GS} = 0V;Tj=25℃ V _{DS} =80V; V _{GS} = 0V;Tj=125℃ | | | 20 250 | μA |
| V _{SDF} | Diode forward voltage | I _{SD} =22A, V _{GS} = 0 V | | | 1.3 | V |

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